CRXF08D065G2

Product Summary

650 V

22 nC

ΗF

8 A



Silicon Carbide Schottky Diode 650 V, 8 A, 22 nC

 V_{RRM}

 I_{F} (T_C=151 °C)

 Q_{C}

Pole

General Description

This product family is CRM's second generation SiC JBS, with lower VF and offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required. It is qualified and manufactured on the productive 6 inch SiC line in China fully owned by CR MICRO.

Features

- \bullet Low conduction loss due to low V_{F}
- \bullet Extremely low switching loss by tiny Q_{C}
- Highly rugged due to better surge current
- Industrial standard quality and reliability

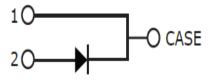
Applications

- Server
- Telecom
- High performance SMPS
- Power factor correction

TO-220F-2



Equivalent circuit



Package Marking and Ordering Information

Part #	Marking	Package		
CRXF08D065G2	CRXF08D065G2	TO-220F-2		



CRXF08D065G2



Silicon Carbide Schottky Diode 650 V, 8 A, 22 nC

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	650	V
Surge Peak Reverse Voltage	V _{RSM}	650	V
DC Peak Reverse Voltage	V _R	650	V
Continuous Forward Current			
$T_{C} = 25^{\circ}C$	I _F	20	^
$T_{C} = 135^{\circ}C$	1 _F	10	A
$T_{C} = 151^{\circ}C$		8	
Non-Repetitive Forward Surge Current			
$T_{c} = 25^{\circ}C, t_{p} = 8.3 \text{ms}, \text{Half Sine Pulse}$	I _{FSM}	64	А
$T_{C} = 110^{\circ}C, t_{p} = 8.3 \text{ms}, \text{Half Sine Pulse}$		56	
Non-Repetitive Forward Surge Current			
$T_{c} = 25^{\circ}C, t_{p} = 8.3 \text{ms}, \text{Half Sine Pulse}$	∫ i ² dt	17	A ² s
$T_{C} = 110^{\circ}C, t_{p} = 8.3 \text{ms}, \text{Half Sine Pulse}$		13	
Power dissipation			
$T_{\rm C} = 25^{\circ}{\rm C}$	P _{tot}	36.6	W
$T_{C} = 110^{\circ}C$		15.8	
Operating junction Range	Τ _j	-55 to +175	°C
Storage temperature Range	${\cal T}_{\sf stg}$	-55 to +150	°C

Maximum Ratings (at Tc = 25 °C, unless otherwise specified)





Thermal Resistance

Parameter	Symbol	Max.	Unit
Thermal resistance, junction – case.	R_{thJC}	4.1	°C/W

Electrical Characteristic (at Tc = 25 °C, unless otherwise specified)

Parameter	Symbol	Value			Unit	Test Condition
Farameter	Symbol	min.	typ.	max.	Onit	
						I _F =8A
Forward Voltage	V _F	-	1.35	1.7	V	T _j =25°C
		-	1.6	-		T _j =175°C
					μA	V _R =650V
Reverse Current	I _R	-	0.5	50		T _j =25°C
		-	10	-		T _j =175°C
Total Capacitive Charge	Q _c	-	22	-	nC	V_{R} =400V, T_{j} =25°C
						$Q_C = \int_0^{V_R} C(V) dV$
Total Capacitance	С				pF	T _j =25℃, f=1MHz
		-	460	-		V _R =0V
		-	44	-		V _R =200V
		-	36	-		V _R =400V







Characteristics Curve:

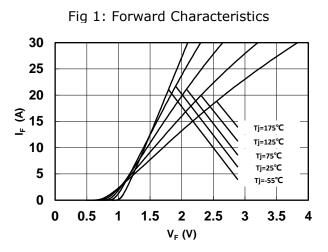


Fig 3: Current Derating

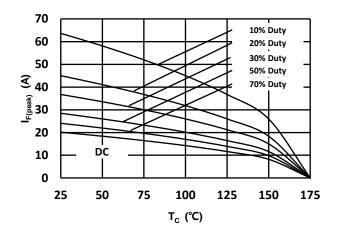
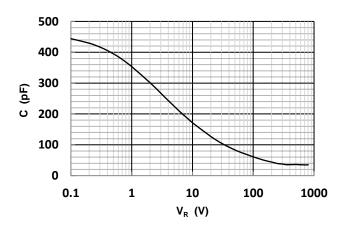
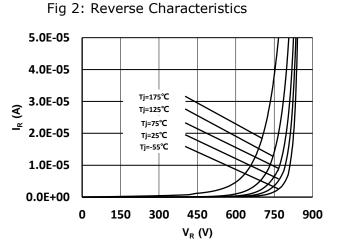


Fig 5: Capacitance vs. Reverse Voltage







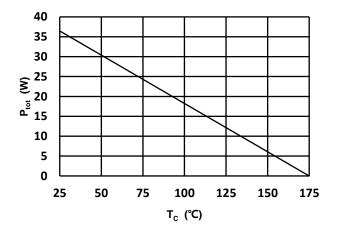


Fig 6: Reverse Charge vs. Reverse Voltage

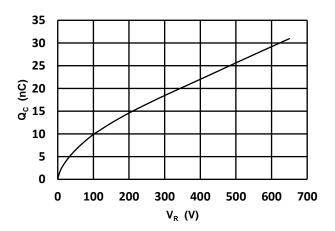
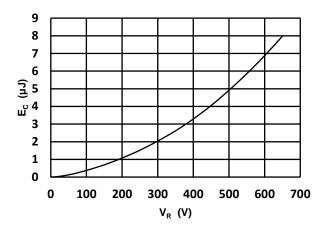




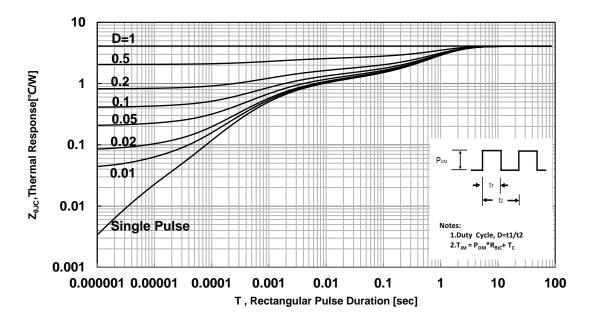




Fig 7: Typical Capacitance Stored Energy



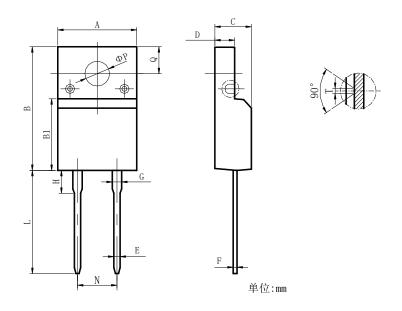








Package Outline: TO-220F-2



Itoma	Values(mm)			
Items	MIN	MAX		
A	9.7	10.3		
В	15.5	16.1		
B1	8.99	9.39		
С	4.4	4.8		
D	2.50	2.90		
E	0.70	0.90		
F	0.40	0.60		
G	1.12	1.42		
Н	3.40	3.80		
L	12.60	13.60		
Ν	4.88	5.28		
Q	3.15	3.55		
Фр	3.00	3.30		
Т		0.20		





Revision History

Revison	Date	Major changes
1.0		Release of formal version.

Warnings

Exceeding the maximum ratings of the device in performance may cause damage to the device, even the permanent failure, which may affect the dependability of the machine. It is suggested to be used under 80 percent of the maximun ratings of the device.

1. When installing the heatsink, please pay attention to the torsional moment and the smoothness of the heatsink.

2. This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.



单击下面可查看定价,库存,交付和生命周期等信息

>>CRMICRO(华润微)